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The electronic and magnetic properties of tetravalent-ion-doped La$_{0.85}$Zr$_{0.15}$MnO$_3$ (LZMO) thin films that were epitaxially grown on SrTiO$_3$ (STO) and MgO substrates were studied using temperature-dependent x-ray diffraction (XRD), x-ray absorption near-edge structure, x-ray linear dichroism, and x-ray magnetic circular dichroism at the Mn $L_{3,2}$- and K-edge. XRD studies reveal that the LZMO thin films have compressive and tensile strains (along the c-axis) on the STO and MgO substrates, respectively. As the temperature is reduced from room temperature to below magnetic transition temperature, the preferentially occupied Mn majority-spin $e_g$ orbital changes from the in-plane $d_{xy}$ to the out-of-plane $d_{3z^2-r_2}$ orbital for LZMO/STO, and vice versa for LZMO/MgO. Experimental results suggest that the new hopping path that is mediated by the Mn$^{2+}$ ions triggers a stronger $d_{3z^2-r_2}$ orbital ordering of Mn$^{3+}$ ions and enhances the ferromagnetic coupling between the Mn spin moments of $t_{2g}$ electrons in LZMO/STO, whereas the strong tensile strain stabilizes the $d_{3z^2-r_2}$ orbital by inducing lattice distortions of the MnO$_6$ octahedra in LZMO/MgO.

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I. INTRODUCTION

Recently, colossal magnetoresistive perovskite manganites, $A_{1-x}B_x$MnO$_3$ ($A$ = trivalent rare earth ions and $B$ = divalent alkaline earth ions), have attracted considerable attention. These materials exhibit a remarkably rich variety of structural, magnetic, and transport properties because of couplings between spin and orbital moments. Solovyev et al. 5 and Millis 6 argued that the magnetic properties of $A_1$, $x$B$_x$MnO$_3$ are determined by the competition between the anti-ferromagnetic (AFM) super-exchange of “$t_{2g}$” core spins and the ferromagnetic (FM) double-exchange (DE) of delocalized “$e_g$” electrons. The core electrons are relatively unaffected by the doping-induced strain, 7,8 oxygen stoichiometry, 9,10 or lattice mismatch. 11–13 However, structural distortions of the MnO$_6$ octahedra can change the electronic structures, which in turn modify the AFM and FM couplings between Mn spins. 13,14 Nanda and Satpathy showed that the lattice mismatch-induced epitaxial strain could cause an anisotropic hopping of electrons between orbitals and change spin orderings. 15 It is been also found that the current research is more focused on understanding the interfacial effects within the epitaxially grown perovskite-oxides thin films and different oriented substrates. 16–19 For instance, Garcia-Barriocanal et al. 18 experimentally observed the induced magnetic moment at the Ti sites in the LaMnO$_3$/SrTiO$_3$ (LMO/STO) epitaxial interface and attributed it to the formation of a new valence state of Ti$^{3+}$ at the LMO/STO epitaxial interface by the transfer of charge from the Mn $d$-band to the empty conduction band of the titanate. To date, theoretical calculations and experimental studies have revealed that suitable doping or proper epitaxial strain can induce orbital ordering in single-crystalline or films of manganites. 11,12,20–22

Many studies of hole-doped manganites have been performed, but studies of electron-doped manganites are fewer, probably because the radii of tetravalent electron-dopants differ greatly from those of the trivalent ions (specifically for “La”). In principle, tetravalent ion-doped LMO manganites can alter the electronic structure of the samples, enhancing the spin ordering of Mn ions and giving rise to a high Curie temperature. However, whether tetravalent dopants have the electron-doping effect in LMO compounds has not been conclusively determined. 23–25 Tetravalent dopants may behave like hole-dopants in LMO compounds. 26–30 Among tetravalent ion-doped LMO compounds, those doped with “Ce” have been the most extensively studied. 27,28 However, Ce doping has a few drawbacks: for example, Ce may exist in Ce$^{3+}$ and Ce$^{4+}$ valence states, changing the oxidation state of the Mn ions. Additionally, the La$_{1-x}$Ce$_x$MnO$_3$ samples are usually multiphase mixtures with CeO$_2$ inclusions. 32 In contrast, the “Zr” dopant has a single valence state of 4+ in La$_{1-x}$Zr$_x$MnO$_3$ manganite. Roy et al. 24 studied La$_{1-x}$Zr$_x$MnO$_3$ samples with various values of x ($x = 0.05–0.2$) and found that increasing the Zr content not only increases electrical conductivity but also enhances the hybridization between Mn $d$ orbitals and O 2$p$ states as well as the magnetic ordering. These results can

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be explained by the DE interaction through Mn$^{2+}$-O-Mn$^{3+}$ and an increase of the Mn$^{2+}$/Mn$^{3+}$ ratio. However, Wang et al. investigated the transport properties of La$_{0.8}$Zr$_{0.2}$MnO$_3$ film and showed that the correlation between magnetic and transport properties is caused by the interaction between Mn$^{3+}$ and Mn$^{4+}$ ions rather than by the interaction between Mn$^{2+}$ and Mn$^{3+}$ ions. Therefore, whether the doping of Zr$^{4+}$ into the LMO matrix generates an electron-doped and/or a hole-doped effect remains a matter of controversy. Multiple valence states of the Mn ions in La$_x$MnO$_3$ and La$_x$Sr$_y$MnO$_3$ thin films have recently been identified, suggesting unconventional charge transport in manganites. Hence, elucidating the underlying coupling mechanisms that govern the transport and magnetic properties of manganites will pave the way for developing new types of spintronic device.

In this study, x-ray diffraction (XRD) and x-ray absorption near-edge structure (XANES) measurements at the Mn K-edge and x-ray linear dichroism (XLD) and x-ray magnetic circular dichroism (XMCD) measurements at the Mn L$_{3,2}$-edge were performed at various temperatures to elucidate the atomic and electronic structures of epitaxially strained La$_{0.85}$Zr$_{0.15}$MnO$_3$ (LZMO) films. These measurements provide insight into the strain-induced preferential orbital occupation and spin character of the Mn ions in the samples of interest.

II. EXPERIMENTAL DETAILS

The crystal structures of the thin films were determined by using high-resolution XRD measurements at beamline-BL07 of the National Synchrotron Radiation Research Center (NSSRC), Hsinchu, Taiwan. X-ray energy was set to be 8 keV using a pair of Si (111) crystals and the beam size was controlled using a pair of slits (horizontal and vertical) in front of the sample. The experimental resolution was further improved by using a perfect crystal Ge (111) as the analyzer. The sample was glued on the cold head of a cryostat that was mounted on an 8-circle diffractometer, and then aligned with the incident photon by the Bragg reflections of the sample. XANES measurements at the Mn K-edge and XLD and XMCD measurements at the Mn L$_{3,2}$-edge were made at various temperatures in three beamlines (BL-17C, 11A, and 20A) at the NSSRC. Mn K-edge XANES spectra were obtained in total fluorescence yield mode, while Mn L$_{3,2}$-edge XANES/XLD/XMCD spectra were obtained in total electron yield mode. Mn L$_{3,2}$-edge XANES measurements were made at two angles of incidence ($\theta$), (a) $\theta = 0^\circ$-normal incidence (such that the electric field $E$ of linearly polarized photons was parallel to the ab-plane of the film), and (b) $\theta = 70^\circ$-grazing incidence (with $E$ almost parallel to the c-axis of the film). The difference between the above two measurements is typically referred to as XLD, and helps to provide insight into the preferential occupation of the Mn majority-spin 3$d$ $e_g$ orbitals that is caused by the anisotropic effects related to various strains. The electrical resistivity and the magnetic properties were measured by the typical method using a four-point probe, a physical property measurement system, and a superconducting quantum interference device (SQUID) magnetometer, respectively. The bulk target of LZMO was prepared using the typical solid state reaction technique. La$_2$O$_3$, ZrO$_2$, and Mn$_2$O$_3$ powders with the La:Zr:Mn ratio of 0.85:0.15:1 were mixed in a mill for 1 h. The mixture was calcined in air at 900°C and later heated for 1100°C for 16 h. To make the target of this powder, it was pressed into pellets of an inch diameter and 0.6 cm thickness. Finally, it was sintered at 1238°C in air for 12 h. The target sample was used in the deposition of LZMO thin films with a thickness of $\sim$300 nm on STO and MgO (001) substrates by RF-sputtering. Post annealing of these as-deposited films in oxygen atmosphere for 30 min and 800°C temperature was carried out in order to improve their crystallinity and to get ensured that the oxygen contents remain intact.

FIG. 1. (a) XRD pattern of bulk LZMO sample. Data are fitted using standard Rietveld technique. (b) and (c) Crystal structure of bulk LZMO with a rhombohedral lattice in space group R-3C and of the LZMO films deposited on STO and MgO substrates with an ABO$_3$ cubic lattice, respectively.
III. RESULTS AND DISCUSSION

The XRD pattern of the bulk LZMO sample reveals a rhombohedral structure with lattice parameters of $a = b = 5.523 \text{ Å}$ and $c = 13.357 \text{ Å}$, following refinement by the Rietveld technique [Figs. 1(a) and 1(b)]. A small peak appeared around $28^\circ$, which might be related to the ZrO$_2$ phase, indicating the difficulty in doping tetravalent-ion in LaMnO$_3$ matrix. Figures 2(a) and 2(b) present the high resolution XRD data through the Bragg peak (002) of the STO and MgO substrates, respectively, taken at $T = 300 \text{ K}$ and 80 K. Notably, in the following discussion of the XRD data and analysis, the pseudo-cubic notation is used for the thin films. The LZMO sample grown on the STO substrate, reflects weakly at approximately $2\theta = 46.505^\circ$, which is indexed as the (002) reflection from LZMO with a pseudo-cubic cell. With the lattice parameters of the substrate as a reference, the out-of-plane lattice mismatch of the LZMO film is calculated using $f = \frac{d_{\text{film}} - d_{\text{sub}}}{d_{\text{sub}}} \times 100\%$, which yields $f = -0.512\%$, a compressive strain, for the STO substrate. XRD measurements were also made at $T = 80 \text{ K}$ [Fig. 2(a)]. The absence of any new reflection suggests that the crystal structure of LZMO remained intact even at 80 K. Figure 2(b) presents XRD measurements of the topography of the LZMO film on MgO substrate at both 300 K and 80 K. In contrast, the reflection from the (002) plane of LZMO grown on STO substrate is at a lower angle than the main Bragg reflection from (002) of MgO (2\text{θ} = 43.187^\circ) is clearly seen. The strain was calculated and found to be $f = 0.689\%$, which represents a tensile strain.

![Figure 2](image)

**FIG. 2.** High-resolution x-ray diffraction data for (a) LZMO/STO and (b) LZMO/MgO at $T = 300 \text{ K}$ and 80 K. Right-inset in (b) presents a mesh scan around (002), confirming reflection (002) from LZMO film on MgO substrate. Left-insets also present atomic force microscopic images of LZMO/STO and LZMO/MgO, respectively.

| TABLE I. Comparison of lattice parameter, mismatch, and strain type of LZMO film grown on substrates of STO and MgO substrates at 300 K and 80 K. |
|-----------------|-----------------|-----------------|-----------------|-----------------|
| LZMO/STO        | 300 K           | 80 K            |
| 2\theta         | 46.753          | 46.505          | 46.846          | 46.530          |
| Lattice parameter (Å) | 3.906          | 3.926          | 3.899          | 3.924          |
| Lattice mismatch, f | -0.512%        | -0.641%        |
| Strain type     | Compressive     | Compressive     |

| LZMO/MgO        | 300 K           | 80 K            |
| 2\theta         | 43.187          | 43.509          | 43.259          | 43.567          |
| Lattice parameter (Å) | 4.211          | 4.182          | 4.205          | 4.176          |
| Lattice mismatch, f | 0.689%         | 0.690%         |
| Strain type     | Tensile         | Tensile         |
to be 260 ± 5 K, while those of LZMO/STO and LZMO/MgO were 270 ± 3 K and 230 ± 3 K, respectively. The fact that LZMO/STO has a slightly higher T_{MI} than that of the bulk sample, whereas LZMO/MgO has a substantially lower T_{MI} than that of the bulk LZMO sample will be discussed below. The resistivity of LZMO/STO is lower than that of LZMO/MgO in the temperature range 5–300 K, suggesting an enhancement of the charge transport of LZMO/STO that involves the higher number of delocalized Mn majority-spin e_g electrons.\(^{41}\) The slope of the curve of the resistivity of LZMO/MgO around RT is much higher than that of LZMO/STO, indicating that a higher polaron hopping energy is required around RT.\(^{42,43}\) This finding reveals that LZMO/MgO undergoes a strong local lattice distortion near RT. The above results together suggest that the substantial difference in T_{MI} and \(d\rho/dT\) near RT between LZMO/STO and LZMO/MgO may arise from the relatively strong tensile strain in LZMO/MgO, as presented in Table I. Figure 3 also indicates the temperature-dependence of magnetization for all studied samples, all of which exhibit similar smooth ferromagnetic-to-paramagnetic transitions. The magnetic transition temperature, T_C, was determined by extrapolating the leading edge of the magnetization-versus-temperature curve to the baseline. The T_C of the bulk LZMO sample was found to be 252 ± 3 K, while those of LZMO/STO and LZMO/MgO were 285 ± 3 K and 255 ± 3 K, respectively. Clearly, the magnetization-versus-temperature curves in Fig. 3 indicate that the magnetization is consistently larger in LZMO/STO than in LZMO/MgO or the bulk LZMO sample over the range of temperatures considered. More interestingly, LZMO/STO and LZMO/MgO exhibit opposite magnetic anisotropy at/below T_C, the former has a larger magnetization along the c-axis, while the latter has a larger magnetization in the ab-plane. The opposite magnetic anisotropy can be related to the different preferential orbital occupancies of the highly directional Mn 3d orbitals in the distorted MnO_6 octahedra owing to a compressive strain in LZMO/STO and a tensile strain in LZMO/MgO. To evidently reconcile the above scenario and better understand the effect of strain on temperature-dependent resistivity and magnetization, the electronic and magnetic properties that are associated with the spin moment of the Mn ions in the LZMO/STO and LZMO/MgO samples were comprehensively studied as described below.

Figures 4(a) and 4(b) present the Mn L_{3,2}-edge XANES spectra of LZMO/STO and LZMO/MgO at two angles of incidence \(\theta = 0^\circ\) (with the electric field E parallel to the ab-plane) and 70^\circ (with the electric field E nearly parallel to the c-axis) at temperatures of 80 K, 250 K, and RT, respectively. Corresponding spectra were obtained for the bulk LZMO, MnO, Mn_2O_3, and MnO_2 powder samples at angle \(\theta = 0^\circ\) at RT for reference. The spectra are primarily

![FIG. 4. (a) and (b) Normalized Mn L_{3,2}-edge XANES spectra of LZMO/STO and LZMO/MgO at two angles of incidence (\(\theta = 0^\circ\) and 70^\circ), at temperatures 80 K, 250 K and RT. Results for bulk LZMO, MnO, Mn_2O_3, and MnO_2 are shown for reference. Bottom panels present corresponding XLD spectra. Schematic in-plane (d_{x^2-y^2}) and out-of-plane (d_{3z^2-r^2}) e_g orbitals are also displayed. Note: small flat plateau region indicated by an arrow/dotted line corresponds to MnO-like/Mn^{2+} valence state.](http://scitation.aip.org/termsconditions)
associated with the Mn $2p \rightarrow 3d$ transition, and the intensity of the main feature is attributable to the density of the unoccupied Mn $3d$-O $2p$ hybridized states. The Mn $L_{3,2}$-edge XANES spectra shown in Figs. 4(a) and 4(b) include two features, an $L_1$-edge around 643 eV and an $L_2$-edge around 653 eV, separated by spin-orbit splitting. The broadening of these two features suggests multiple valence states of the Mn ions.\textsuperscript{29} The Mn $L_{3,2}$-edge composes $t_{2g}$ and $e_g$ states owing to the crystal-field splitting. The general features at the Mn $L_{1,2}$-edge of LZMO/STO and LZMO/MgO are similar to those of bulk LZMO and the superposed spectra of MnO, Mn$_2$O$_3$ and MnO$_2$, with a large contribution from Mn$_2$O$_3$, indicative of the presence of both Mn$^{3+}$ and Mn$^{4+}$ states. Therefore, the most likely FM coupling in these samples involves Mn$^{3+}$/Mn$^{4+}$ mixed valence states; this claim is in good agreement with those made elsewhere for tetravalent-ion hole-doped manganites.\textsuperscript{28,29,33} Additionally, the spectra also show the MnO-like/Mn$^{2+}$ state in LZMO/STO and LZMO/MgO, as evidenced by a plateau at approximately 640 eV indicated by an arrow/dotted line in Figs. 4(a) and 4(b), although this plateau was not very well resolved in the Mn $L_1$-edge XANES spectra. Another signature of the Mn$^{2+}$ valence state in LZMO films was verified in the Mn $K$-edge XANES spectra at 80 K and RT at two angles of incidence $\theta = 0^\circ$ and $70^\circ$ in Figs. 5(a) and 5(b), which include three important features A, B, and C. The pre-edge features A to B below the main feature C arise from the Mn 1s transition into unoccupied Mn 3d and/or Mn 3d/4p hybridized states, which have $p$ components that are projected at the Mn sites, as observed in many transition metal oxides.\textsuperscript{44} The main feature C at the Mn $K$-edge corresponds to the high-energy Mn 4$p$ states. To obtain a comprehensive understanding of the position of this feature, the insets in Figs. 5(a) and 5(b) present its derivative. If mainly Mn$^{3+}$ and Mn$^{4+}$ valence states were involved, the FM coupling in LZMO/STO and LZMO/MgO for which the Mn ions in these samples will be assigned to have a valence charge between +3 and +4. The thresholds of features will have higher energy than that of Mn$O_2$/Mn$^{3+}$, but have lower energy than that of Mn$O_2$/Mn$^{4+}$. Clearly, the energy thresholds of the Mn $K$-edge features of the LZMO/STO, LZMO/MgO, and bulk LZMO samples are higher than that of Mn$O$/Mn$^{3+}$, but are lower than that of Mn$O_2$/Mn$^{4+}$, and nearly equal to that of Mn$O_2$/Mn$^{3+}$ at both $\theta = 0^\circ$ and $70^\circ$ as well as at temperatures 80 K and RT. Notably, the threshold energy of the features of LZMO/STO and LZMO/MgO is close to the mean of the features of MnO, Mn$O_3$, and MnO$_2$, as presented in Figs. 5(a) and 5(b). The above results clearly suggest that the LZMO/STO and LZMO/MgO samples contain Mn ions in multiple valence states of Mn ions (Mn$^{3+}$, Mn$^{4+}$, and Mn$^{2+}$). However, it is noteworthy to mention here that the dominant valence states of Mn ions are Mn$^{3+}$ and Mn$^{4+}$, while Mn$^{2+}$ is less abundant. For LZMO/STO, the intensity of the main feature at the Mn $L_{1,2}$-edge with the $E$ field polarized in the $ab$-plane ($\theta = 0^\circ$) at RT is larger than that along the $c$-axis ($\theta = 70^\circ$); whereas for LZMO/MgO, the intensity is larger when the polarization of the $E$ field is along the $c$-axis ($\theta = 70^\circ$), as shown in Figs. 4(a) and 4(b). The structural distortions that are caused by compressive or tensile strains are generally believed to tune the splitting of the crystal field and modulate the preferential orbital occupancy of the highly directional Mn 3$d$ orbitals in the strained manganites.\textsuperscript{21} Aruta et al. argued that Mn$^{1+}$ (3$d^5$) and Mn$^{2+}$ (3$d^6$) ions with high spin configuration are Jahn-Teller-inactive ions, which do not distort the octahedral symmetry. Therefore, these Mn ions are expected not to contribute significantly to the orbital anisotropy. Accordingly, only the effect of the Mn$^{3+}$ (3$d^5$) ions on the orbital anisotropy should

![Figure 5](image-url)
be taken into account in the analysis of the XLD spectra.\textsuperscript{36} However, the sign, intensity, and line-shape of XLD is strongly dependent on the orbital ordering, which can be affected due to local distortion, crystal-field splitting, and anisotropic hopping integral.\textsuperscript{45} In general, the line-shape of XLD can be altered for various MnO\textsubscript{6}octahedra systems, they are closely related to sample structural, chemical elements, composition\textsuperscript{34} and strain,\textsuperscript{46} so on. Importantly, it is worth to note that the sign of XLD integral intensity for similar local atomic structures should be consistent if they are preferable to have same orbital occupations.

Theoretical and experimental studies of the strained manganites have established that structural distortions of the unit cells are the major cause of the lowering of the energy of either the out-of-plane \(e_g\) orbital, \(d_{3z^2-\gamma^2}\), or the in-plane \(e_g\) orbital, \(d_{\gamma^2-\gamma^2}\). The bottom panels in Figs. 4(a) and 4(b) display the XLD spectra (between \(\theta = 0^\circ\) and \(70^\circ\)) at RT, 250 K, and 80 K, which are above, near, and below the transition temperatures of \(T_{MI}\) and \(T_C\), respectively. These spectra provide information on the preferential Mn 3d-orbital occupancy under the influence of strains, due to the STO and MgO substrates. Clearly, the intensities of the XLD spectra of LZMO/STO greatly exceed those of LZMO/MgO at both RT and 80 K, consistent with the presence of more delocalized majority-spin \(e_g\) electrons in LZMO/STO, which was implied by resistivity measurements in Fig. 3. The sign of the XLD feature in the LZMO/STO spectrum is positive, suggesting that the in-plane Mn \(d_{\gamma^2-\gamma^2}\) orbital is preferentially occupied by electrons at RT, while that of LZMO/MgO is negative, suggesting preferential occupation of the out-of-plane Mn \(d_{3z^2-\gamma^2}\) orbital at RT (above the transition temperatures). However, at 80 K (below the transition temperature), the signs of the XLD spectra are reversed. Close to the transition temperatures of \(T_{MI}\) and \(T_C\), the XLD spectra of the samples at 250 K fluctuate between positive and negative values, suggesting that the two Mn majority-spin \(e_g\) orbitals are roughly equally occupied. The XLD results reveal that, for LZMO/STO, as the temperature is reduced from RT to less than the transition temperature of 80 K, the preferential occupancy of the majority-spin \(e_g\) orbitals changes from the in-plane \(d_{3z^2-\gamma^2}\) to the out-of-plane \(d_{\gamma^2-\gamma^2}\); whereas for LZMO/MgO, the change is in the opposite direction. These experimental findings can be understood as being caused by the stabilization of the out-of-plane \(3z^2-\gamma^2\) (in-plane \(\gamma^2-\gamma^2\)) orbital that is induced by the compressive (tensile) strain that arises from a reduction of Coulomb repulsion interaction between Mn ions and O ligands.\textsuperscript{36} This result can be associated with the magnetization anisotropy results in Fig. 3. Notably, similar strain- and temperature-induced changes in the sign of XLD intensity have been observed in BiFeO\textsubscript{3}/DyScO\textsubscript{3} (\(c/a = 1.005\)), BiFeO\textsubscript{3}/NdScO\textsubscript{3} (\(c/a = 0.981\)) thin films,\textsuperscript{39} and \(La_0.5Sr_{0.5}FeO_3\) film that is epitaxially grown on STO substrate below and above the Néel temperature.\textsuperscript{50}

The top five panels of Figs. 6(a) and 6(b) present the Mn \(L_{3,2}\)-edge XANES spectra, with the photo-helicity of the incident x-rays parallel (\(\mu_\parallel\)) and anti-parallel (\(\mu_\perp\)), respectively, to the direction of magnetization of the LZMO/STO and LZMO/MgO samples. These spectra were obtained at 80 K, 200 K, 230 K, 250 K, and RT at angle of incidence \(\theta = 30^\circ\) under an applied magnetic field of 1 Tesla parallel to the surface of the samples. The bottom panels of Figs. 6(a) and 6(b) present the Mn \(L_{3,2}\)-edge XMCD spectra, which reveal that both samples have the same FM phase below the transition temperature \(T_C\). Although quantitative information concerning the spin and orbital moments of the Mn ions in the samples can be obtained principally by analyzing the XMCD curves using spin and orbital sum-rules,\textsuperscript{51,52} the spin and orbital moments that are associated with the multiple valence states of Mn ions cannot be determined directly and accurately from the XMCD spectra by applying these sum-rules.\textsuperscript{33} Therefore, the calculations made by applying the sum-rules to the XMCD spectra are not presented herein.
Nevertheless, the spin moment of the Mn ions can still be inferred from the intensity of XMCD and the general line-shape of the XMCD spectra. The integrated intensity of the XMCD feature (in the energy range 636–643 eV) at the Mn $L_{2,3}$-edge in LZO/STO is approximately twice that of LZO/MgO at/below $T_C$ [see Fig. 7(a)]. Clearly, the greater XMCD intensity at the Mn $L_{2,3}$-edge observed in LZO/STO is consistent with the larger magnetization observed in LZO/STO in the ferromagnetic state, as shown in Fig. 3. The general features in the XMCD spectra in the bottom panels of Figs. 6(a) and 6(b) are quite similar to those of $L_{2,3}$,2-edge in LZO/STO is approximately twice that of LZO/MgO, the former has more delocalized majority-spin $t_{2g}$ electrons and, consequently, greater FM coupling and better transport properties. Figure 7(a) compares the integrated XMCD intensity with the magnetization measurements that are presented in Fig. 3. The variation of the integrated XMCD intensities with temperature below $T_C$ for the LZO/STO and LZO/MgO samples is consistent with the general trend of the temperature-dependent magnetization, as displayed in Fig. 3. As the temperature is reduced, the magnetization is enhanced, as revealed by the increase in the XMCD intensity, which is consistent with the SQUID results.

Recently, Garcia-Barriocanal et al. have found direct evidence of the effect of the interface on the magnetic properties of the LMO/STO epitaxial system. At the interface between titanate and manganite, the Mn-O-Ti bond may provide a means of interaction between the highly localized majority-spin $t_{2g}$ electrons of Mn ions and the 3$d$ electrons of Ti ions by delocalizing the Mn majority-spin $e_g$ electrons. To understand the possible effect of charge transfer on the magnetic properties of LZO/STO, Fig. 7(b) presents the Ti $L_{2,3}$-edge XANES spectra with the photo-helicity of incident x-rays parallel ($\mu_+$) and anti-parallel ($\mu_-$) to the direction of magnetization. The figure also presents the XMCD feature (in the energy range 636–643 eV) at the Mn $L_{2,3}$-edge in LZO/STO, was found and no clear XMCD signal is detected, as shown in the bottom panel of Fig. 7(b).

Notably, Fig. 7(a) involves two experimental techniques, measurement by SQUID and the determination of XMCD intensity at the Mn L$_{3,2}$-edge. Even though these two techniques have different characteristic probe depths, they reveal similar temperature-dependent magnetic properties of the LZMO/STO and LZMO/MgO samples, verifying the consistency of measurements.

IV. CONCLUSION

In summary, this investigation demonstrated that the LZMO thin films epitaxially grown on the STO and MgO substrates have compressive and tensile strain (along c-axis), respectively, and behave more like a hole-doped system with Mn ions in Mn$^{3+}$ and Mn$^{4+}$ valence states. Also Mn$^{2+}$ ions are present but in small amounts. As the temperature is decreased from RT to below $T_C$, for LZMO/STO, the preferential occupancy changes from the in-plane $d_{x^2-y^2}$ orbital to the out-of-plane $d_{x^2-y^2}$ orbital; whereas for LZMO/MgO, the opposite change occurs. The new charge hopping mechanism that is activated by the Mn$^{2+}$ ions is found to have an important role in a preferential occupation of the $d_{x^2-y^2}$ orbital, and in the enhancement of $T_C$ and conductivity, in LZMO/STO, whereas the strong tensile strain stabilizes the $d_{x^2-y^2}$ orbital by causing lattice distortions of the MnO$_6$ octahedra in LZMO/MgO. Therefore, one can tailor the electronic and magnetic properties of epitaxially grown LZMO thin films by simply using different substrates.

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